

Vishay Semiconductors

Hyperfast Rectifier, 8 A FRED Pt[®]





2L TO-220AC Base cathode 2 Q 30 Cathode Anode



VS-8E2TH06

Cathode Anode VS-8E2TH06FP

01

20

| PRODUCT SUMMARY | | | | | | |
|----------------------------------|---------------------------|--|--|--|--|--|
| Package | 2L TO-220AC, 2L TO-220 FP | | | | | |
| I _{F(AV)} | 8 A | | | | | |
| V _R | 600 V | | | | | |
| V _F at I _F | 2.5 V | | | | | |
| t _{rr} (typ.) | 17 ns | | | | | |
| T _J max. | 175 °C | | | | | |
| Diode variation | Single die | | | | | |

FEATURES

- Hyperfast recovery time, reduced Qrr and soft recovery
- 175 °C maximum operating junction temperature
- For PFC CRM/CCM operation
- True 2 pin package
- · Low forward voltage drop
- Low leakage current
- Fully isolated package (V_{INS} = 2500 V_{RMS})
- Compliant to RoHS directive 2002/95/EC
- Halogen-free according to IEC 61249-2-21 definition
- · Designed and gualified for industrial level

DESCRIPTION/APPLICATIONS

State of the art hyperfast recovery rectifiers designed with optimized performance of forward voltage drop and hyperfast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC boost stage in the ac-to-dc section of SMPS, inverters or as freewheeling diodes.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

| ABSOLUTE MAXIMUM RATINGS | | | | | | | |
|---|-----------------------------------|-------------------------|-------------|-------|--|--|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS | | | |
| Peak repetitive reverse voltage | V _{RRM} | | 600 | V | | | |
| Average rectified forward current | 1 | T _C = 133 °C | 8 | • | | | |
| FULL-PAK | IF(AV) | T _C = 78 °C | 0 | | | | |
| Non-repetitive peak surge current | I _{FSM} | T _J = 25 °C | 70 | A | | | |
| Peak repetitive forward current | I _{FM} | | 16 | | | | |
| Operating junction and storage temperatures | T _J , T _{Stg} | | - 65 to 175 | °C | | | |

| ELECTRICAL SPECIFICATIONS (T _J = 25 $^{\circ}$ C unless otherwise specified) | | | | | | | | |
|--|-------------------------------------|---|------|------|------|-------|--|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS | | |
| Breakdown voltage, blocking voltage | V _{BR} , V _R | I _R = 100 μA | 600 | - | - | | | |
| Forward voltage | VF | I _F = 8 A | - | 2.1 | 2.5 | V | | |
| | ۷F | I _F = 8 A, T _J = 150 °C | - | 1.6 | 1.9 | | | |
| Deverse leekees eurrent | 1 | $V_{R} = V_{R}$ rated | - | 0.2 | 35 | | | |
| Reverse leakage current I _R | | $T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$ | - | 50 | 350 | μA | | |
| Junction capacitance | CT | V _R = 600 V | - | 6 | - | pF | | |
| Series inductance | L _S | Measured lead to lead 5 mm from package body | - | 8 | - | nH | | |



HALOGEN FREE



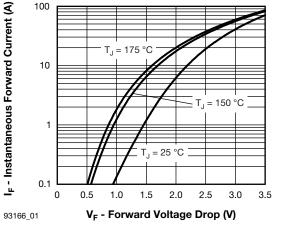
Vishay Semiconductors Hyperfast Rectifier, 8 A FRED Pt®

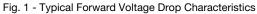
| DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 $^{\circ}$ C unless otherwise specified) | | | | | | | | |
|---|-------------------------------------|---|--|------|------|-------|----|--|
| PARAMETER | SYMBOL | TEST C | MIN. | TYP. | MAX. | UNITS | | |
| | | I _F = 1.0 A, dI _F /dt | = 100 A/µs, V _R = 30 V | - | 17 | 23 | | |
| | | I _F = 8.0 A, dI _F /dt | = 100 A/µs, V _R = 30 V | - | 22 | 25 | | |
| | | T _J = 25 °C | $I_F = 8 A$ | - | 22 | - | | |
| Reverse recovery time | t _{rr} | | dl _F /dt = 200 A/μs V _R = 390 V | - | 43 | - | ns | |
| | | T _J = 125 °C | I _F = 8 A dI _F /dt = 600 A/μs V _R = 390 V | - | 33 | - | | |
| | | T _J = 25 °C | $I_F = 8 A$ | - | 3.1 | - | | |
| Peak recovery current | I _{BBM} | | — dI _F /dt = 200 A/μs V _R = 390 V | - | 5.2 | - | А | |
| Peak recovery current | KKM | T _J = 125 °C | I _F = 8 A dI _F /dt = 600 A/µs V _R = 390 V | - | 13 | - | ~ | |
| Reverse recovery charge | | T _J = 25 °C | $I_F = 8 A$ | - | 32 | - | | |
| | rse recovery charge Q _{rr} | | dl _F /dt = 200 A/μs V _R = 390 V | - | 120 | - | nC | |
| | Qrr | T _J = 125 °C | I _F = 8 A dI _F /dt = 600 A/μs V _R = 390 V | - | 230 | - | | |

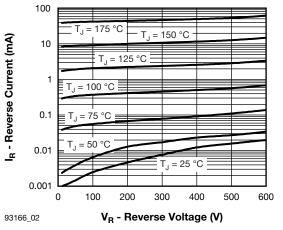
| THERMAL - MECHANICAL SPECIFICATIONS | | | | | | | | |
|--|-----------------------------------|--|----------|----------------------|------------|------------------------|--|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS | | |
| Maximum junction and storage temperature range | T _J , T _{Stg} | | - 65 | - | 175 | °C | | |
| Thermal resistance, | Р | | - | 2 | 2.4 | | | |
| junction to case FULL-PAK | R _{thJC} | | - | 5 | 5.5 | | | |
| Thermal resistance, junction to ambient per leg | R _{thJA} | Typical socket mount | - | - | 70 | °C/W | | |
| Typical thermal resistance, case to heatsink | R _{thCS} | Mounting surface, flat, smooth and greased | - | 0.5 | - | | | |
| Walaht | | | - | 2 | - | g | | |
| Weight | | | - | 0.07 | - | oz. | | |
| Mounting torque | | | 6 (5) | - | 12 (10) | kgf · cm (lbf · in) | | |
| | | Case style TO-220 | | 8E2TH06 8E2TH06FP | | | | |
| Marking device | | Case style TO-220 FULL-PAK | | | | | | |



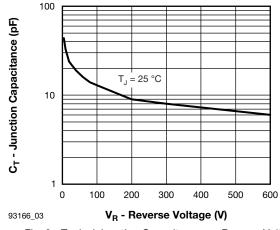
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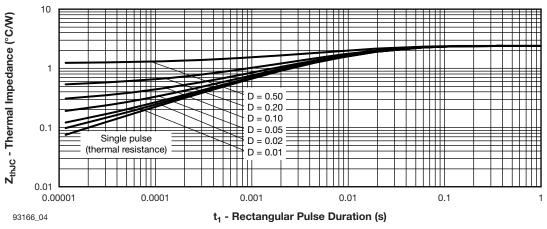
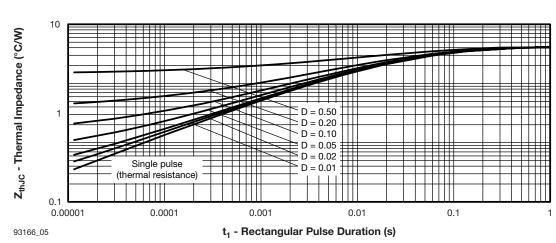


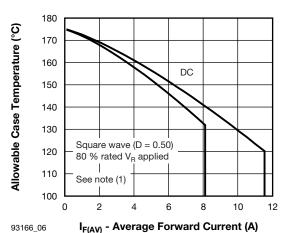
Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (TO-220)



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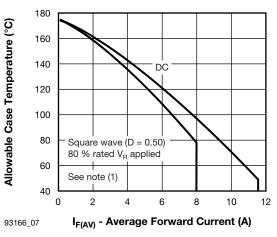


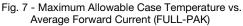






Average Forward Current (TO-220)





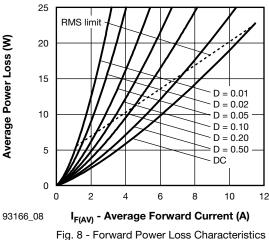


Fig. 8 - Forward Power Loss Characteristics

Note

⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; Pd = Forward power loss = $I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6); Pd_{REV} = Inverse power loss = $V_{R1} \times I_R$ (1 - D); I_R at V_{R1} = Rated V_R



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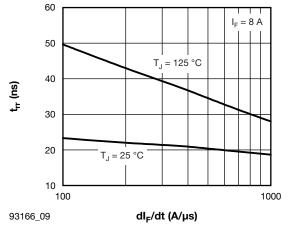


Fig. 9 - Typical Reverse Recovery Time vs. dI_F/dt

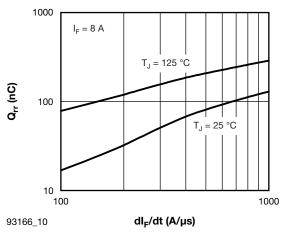


Fig. 10 - Typical Stored Charge vs. dI_F/dt

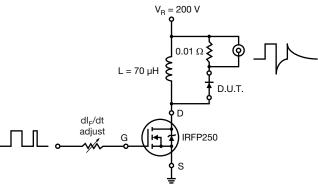
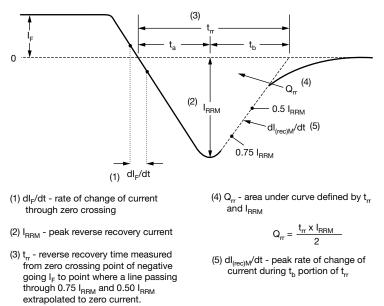
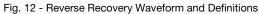


Fig. 11 - Reverse Recovery Parameter Test Circuit





Vishay Semiconductors Hyperfast Rectifier, 8 A FRED Pt®



ORDERING INFORMATION TABLE

| Device code | vs- | 8 | Е | 2 | т | Н | 06 | FP | -E |
|-------------|--|------|----------|------------|----------|----------|-----------|---------|--------|
| | | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 |
| | Vishay Semiconductors product suffix Current rating (8 = 8 A) | | | | | | | | |
| | 3 - Circuit configuration: E = Single diode | | | | | | | | |
| | 4 - | | • | pin pack | age | | | | |
| | 5 - | T = | TO-220 |) | | | | | |
| | 6 - | H = | Hyperfa | ast recov | very tim | е | | | |
| | 7 - | Volt | age coo | de (06 = | 600 V) | | | | |
| | 8 - • None = TO-220 | | | | | | | | |
| | | • F | P = FUI | _L-PAK | | | | | |
| | 9 - | Env | rironmer | ntal digit | : | | | | |
| | | • - | E = Ro⊦ | IS comp | liant an | d termir | nations I | ead (Pb |)-free |

• -M = Halogen-free, RoHS compliant and terminations lead (Pb)-free

| ORDERING INFORMATION (Example) | | | | | | | |
|--|----|------|--------------------------|--|--|--|--|
| PREFERRED P/N QUANTITY PER TUBE MINIMUM ORDER QUANTITY PACKAGING DESCR | | | | | | | |
| VS-8E2TH06-E | 50 | 1000 | Antistatic plastic tubes | | | | |
| VS-8E2TH06-M | 50 | 1000 | Antistatic plastic tubes | | | | |
| VS-8E2TH06FP-E | 50 | 1000 | Antistatic plastic tubes | | | | |

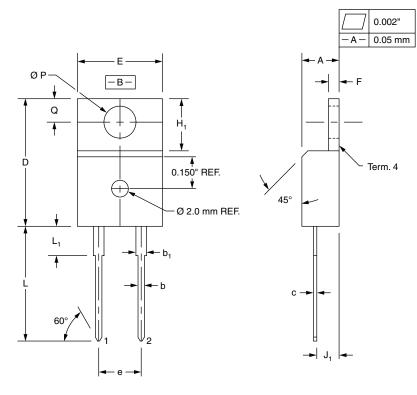
| LINKS TO RELATED DOCUMENTS | | | | | | |
|----------------------------|-----------------|--------------------------|--|--|--|--|
| Dimensions | TO-220AC | www.vishay.com/doc?95259 | | | | |
| Dimensions | TO-220 FULL-PAK | www.vishay.com/doc?95260 | | | | |
| Part marking information | TO-220AC | www.vishay.com/doc?95391 | | | | |
| Fait marking mornation | TO-220 FULL-PAK | www.vishay.com/doc?95392 | | | | |
| Packaging information | | www.vishay.com/doc?95388 | | | | |

Vishay High Power Products

True 2 Pin TO-220

DIMENSIONS in millimeters and inches

VISHAY



| SYMBOL | MILLIN | IETERS | INCH | ES | |
|-------------------------------|--------|--------|-----------|-------|--|
| STMDUL | MIN. | MAX. | MIN. | MAX. | |
| A | 4.32 | 4.57 | 0.170 | 0.180 | |
| b | 0.71 | 0.91 | 0.028 | 0.036 | |
| b ₁ | 1.15 | 1.39 | 0.045 | 0.055 | |
| С | 0.36 | 0.53 | 0.014 | 0.021 | |
| D | 14.99 | 15.49 | 0.590 | 0.610 | |
| E | 10.04 | 10.41 | 0.395 | 0.410 | |
| e | 5.08 | BSC | 0.200 BSC | | |
| F | 1.22 | 1.37 | 0.048 | 0.054 | |
| H ₁ | 5.97 | 6.47 | 0.235 | 0.255 | |
| J ₁ | 2.54 | 2.79 | 0.100 | 0.110 | |
| L | 13.47 | 13.97 | 0.530 | 0.550 | |
| L ₁ ⁽¹⁾ | 3.31 | 3.81 | 0.130 | 0.150 | |
| ØP | 3.79 | 3.88 | 0.149 | 0.153 | |
| Q | 2.60 | 2.84 | 0.102 | 0.112 | |

Notes

 $^{\left(1\right)}$ Lead dimension and finish uncontrolled in L_{1}

• These dimensions are within allowable dimensions of JEDEC TO-220AB rev. J outline dated 3-24-87

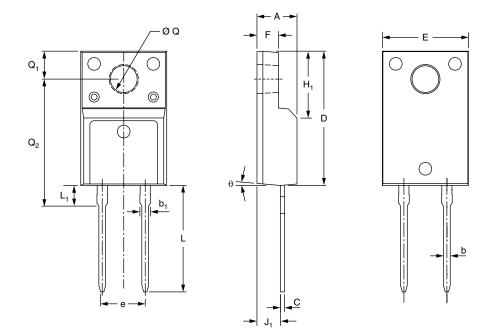
Controling dimension: Inch

Vishay High Power Products

True 2 Pin TO-220 FULL-PAK

DIMENSIONS in millimeters and inches

VISHAY



| SYMPOL | MILLIN | METERS | INCH | IES |
|----------------|--------|---------|----------|--------|
| SYMBOL | MIN. | MAX. | MIN. | MAX. |
| A | 4.53 | 4.93 | 0.178 | 0.194 |
| b | 0.71 | 0.91 | 0.028 | 0.036 |
| b ₁ | 1.15 | 1.39 | 0.045 | 0.055 |
| С | 0.36 | 0.53 | 0.014 | 0.021 |
| D | 15.67 | 16.07 | 0.617 | 0.633 |
| E | 9.96 | 10.36 | 0.392 | 0.408 |
| e | 5.08 | typical | 0.200 ty | ypical |
| F | 2.34 | 2.74 | 0.092 | 0.107 |
| H ₁ | 6.50 | 6.90 | 0.256 | 0.272 |
| J ₁ | 2.56 | 2.96 | 0.101 | 0.117 |
| L | 12.78 | 13.18 | 0.503 | 0.519 |
| L ₁ | 2.23 | 2.63 | 0.088 | 0.104 |
| ØQ | 2.98 | 3.38 | 0.117 | 0.133 |
| Q ₁ | 3.10 | 3.50 | 0.122 | 0.138 |
| Q2 | 14.80 | 15.20 | 0.583 | 0.598 |
| θ | 0° | 5° | 0° | 5° |



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